

TP869C04R

FUJI Diode

Schottky Barrier Diode

Maximum Rating and Characteristics

• Maximum ratings (at Ta=25°C unless otherwise specified.)

Item	Symbols	Conditions	Ratings	Units
Repetitive peak reverse voltage	VRRM	-	45	V
Average output current	lo	50Hz square wave duty =1/2 Tc =120°C	40*	A
Non-repetitive forward surge current**	IFSM	Sine wave, 10ms 1shot	190	А
Operating junction temperature	Tj	-	150	°C
Storage temperature	Tstg	-	-40 to +150	°C

Note* Out put current of center tap full wave connection.

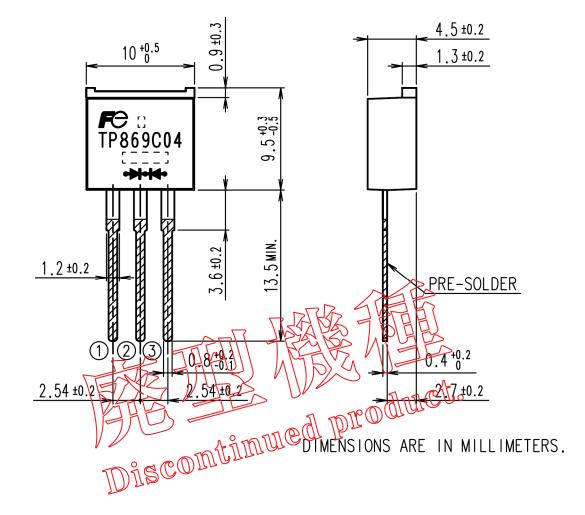
Note** Rating per element

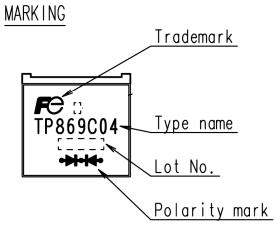
• Electrical characteristics (at Ta=25°C unless otherwise specified.)

Item	Symbols	Conditions	Maximum	Units			
Forward voltage***	VF	IF = 20 A	0.61	V			
Reverse current***	IR		200	μA			
Thermal resistance	Rth(j-c)	Junction to case	1.00	°C/W			
Mechanical characteristics							
Item		Condition	Maximum	Units			
Approximate mass 7779	17 Q(AL TOIL OF	1.6	g			
Approximate mass Discomt	IMUG	9° 2					

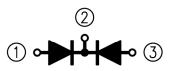
Outline Drawings [mm]

OUT VIEW

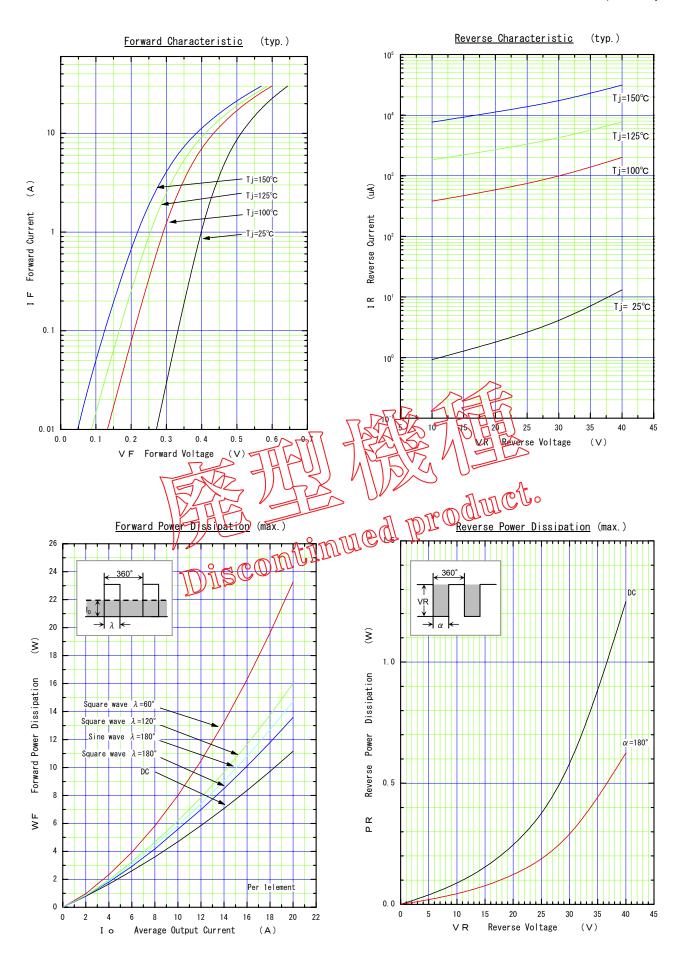




CONNECTION



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